Best Available Copy U.S. UTILITY Patent Application

PATENT NUMBER and ISSUE DATE

WHICH IS A DIV OF 08/956,950 10/23/1997 PAT 6,249,012 WHICH IS A DIV OF 08/556,232 11/09/1995 PAT 5,733,796 WHICH IS A CON OF 08/179,242 01/10/1994 ABN	APPL NUM 10052347	FILING DATE 01/23/2002	CLASS 438	SUBCLASS	GAU 2812	[4.]	EXAMINER		
**CONTINUING DATA VERIFIED: THIS APPLICATION IS A CON OF 09/677,781 10/02/2000 WHICH IS A DIV OF 09/417,778 10/14/1999 WHICH IS A DIV OF 08/956,950 10/23/1997 PAT 6,249,012 WHICH IS A DIV OF 08/556;232 11/09/1995 PAT 5,733,796 WHICH IS A CON OF 08/179,242 01/10/1994 ABN WHICH IS A DIV OF 07/926,C22 08/07/1992 PAT 5,278,433 WHICH IS A CON OF 07/661,304 02/27/1991 ABN **FOREIGN APPLICATIONS VERIFIED: APAN P050209/1990 02/28/1990 APAN P050210/1990 02/28/1990 APAN P050210/1990 02/28/1990 APAN P050211/1990 02/28/1990 G-PUB DO NOT PUBLISH	71		Katsuhio imoto Ma	le; Mabuchi Al safumi; Akasa	kira; Ka ki Isam	to Hisaki; \$ u;	Sassa Michinari;	Koide	
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TLE : Method for manufacturing a gallium nitride group compound semiconductor	5 USC 119 conditio	ns met	□ yes			ATTORNE	Y DOCKET NO		
U.S.DEPT, OF COMM.PAT.&TM-PTO-436L(Rev. 12.94)				nitride group c				c	
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NOTICE OF ALLOWANCE MAILED		CLAIMS ALLOWED					
	Assistant Examiner	Total Claims	Pri O.	int Claim for G			
ISSUE FEE		DRAWING					
Amount Due Date Paid		Sheets Drwg.	Figs.Drwg.	Print Fig.			
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TERMINAL	PREPARED FOR ISSUE	PREPARED FOR ISSUE Application Examiner					
DISCLAMER	WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368, Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.						
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